NSN 5961-01-352-7864

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-352-7864 **Inclosure Material:** Ceramic or plastic **Overall Length:** 1.375 inches **Overall Height:** 0.260 inches **Overall Width:** 0.750 inches **Component Name And Quantity:** 2 semiconductor device diode and 1 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon single transistorsilicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 400.0 drain to source voltage single transistor400.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 8.00 amperes source cutoff current preset all semiconductor device diode15.00 amperes source cutoff current of standard range all transistor **Terminal Type And Quantity:** 6 uninsulated wire lead **Specification Data:** 02750-kkd327 manufacturers source control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No